

PRMH11-Q

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

4 August 2025

Product data sheet

1. General description

NPN/NPN Resistor-Equipped double Transistors (RET) in an ultra small DFN1412-6 (SOT1268) leadless Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Digital applications
- Cost-saving alternative to BC847/BC857 series in digital applications
- · Control of IC inputs
- Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor	er transistor						
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
Io	output current			-	-	100	mA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 5 mA; T _{amb} = 25 °C		30	-	-	
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	8.0	1	1.2	

[1] See section "Test information" for resistor calculation and test conditions.



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		O1 I2 GND2
2	I1	input (base) TR1	1 7 6	
3	O2	output (collector) TR2		R1 R2
4	GND2	GND (emitter) TR2	[2] [5]	TR2
5	12	input (base) TR2	3 8 4	TR1 R2 R1
6	01	output (collector) TR1		
7	01	output (collector) TR1	Transparent top view	
8	O2	output (collector) TR2	DFN1412-6 (SOT1268)	GND1 I1 O2 sym063

6. Ordering information

Table 3. Ordering information

Type number	Package	ckage					
	Name	Description	Version				
PRMH11-Q	DFN1412-6	plastic, thin small outline package; no leads; 6 terminals; 1.4 mm x 1.2 mm x 0.47 mm body	SOT1268				

7. Marking

Table 4. Marking codes

Type number	Marking code
PRMH11-Q	В9

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

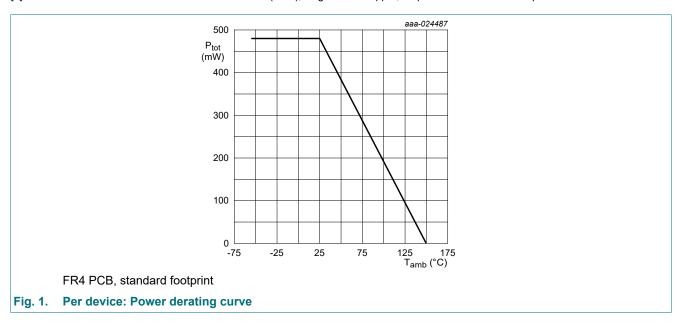
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or					
V _{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V_{EBO}	emitter-base voltage	open collector		-	10	V
V _I	input voltage	positive		-	40	V
		negative		-	-10	V
Io	output current			-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	325	mW
Per device	·		·			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
Per device							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

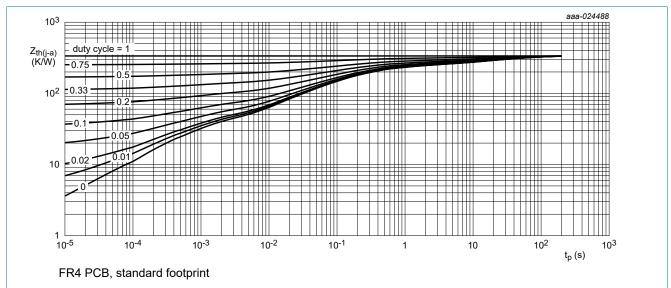


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

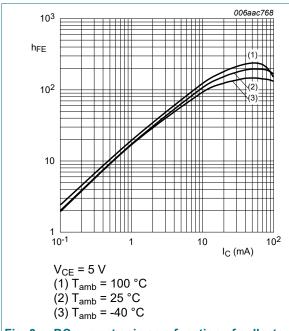
50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	1	μΑ
	current	V _{CE} = 30 V; I _B = 0 A; T _j = 150 °C		-	-	5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	400	μA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 5 mA; T _{amb} = 25 °C		30	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	150	mV
V _{I(off)}	off-state input voltage	V _{CE} = 5 V; I _C = 100 μA; T _{amb} = 25 °C		-	1.1	0.8	V
V _{I(on)}	on-state input voltage	V _{CE} = 0.3 V; I _C = 10 mA; T _{amb} = 25 °C		2.5	1.8	-	V
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	-	2.5	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	230	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor



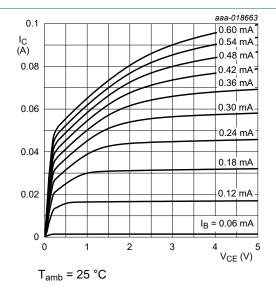
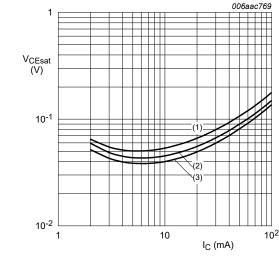


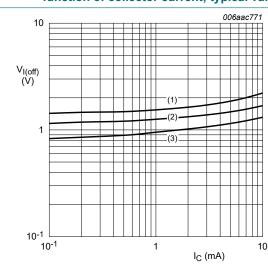
Fig. 4. Collector current as a function of collectoremitter voltage; typical values

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω



I_C/I_B = 20 (1) T_{amb} = 100 °C (2) T_{amb} = 25 °C (3) T_{amb} = -40 °C

Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values

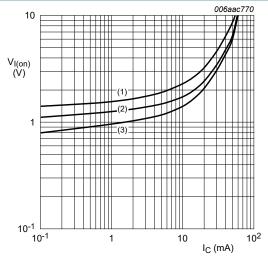


 $V_{CE} = 5 V$

(1) $T_{amb} = -40 \,^{\circ}\text{C}$ (2) $T_{amb} = 25 \,^{\circ}\text{C}$

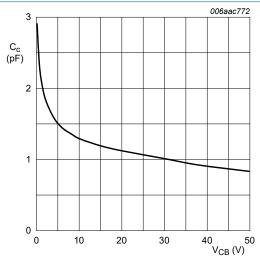
(3) $T_{amb} = 100 \, ^{\circ}C$

Fig. 7. Off-state input voltage as a function of collector current; typical values



V_{CE} = 0.3 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C (3) T_{amb} = 100 °C

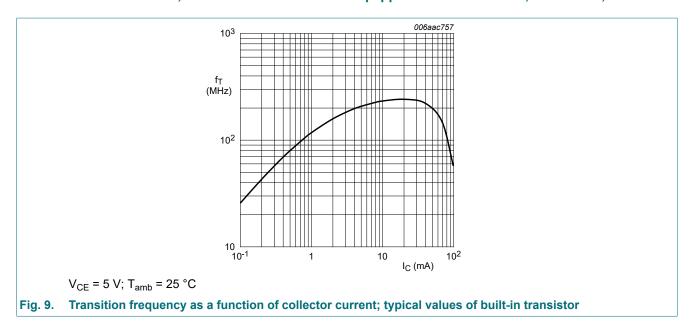
Fig. 6. On-state input voltage as a function of collector current; typical values



 $f = 1 MHz; T_{amb} = 25 °C$

Fig. 8. Collector capacitance as a function of collectorbase voltage; typical values

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11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{I})}{I_{2} - I_{I}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

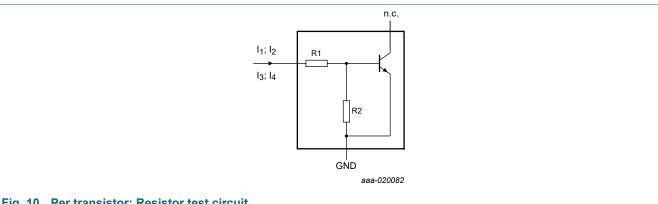


Fig. 10. Per transistor: Resistor test circuit

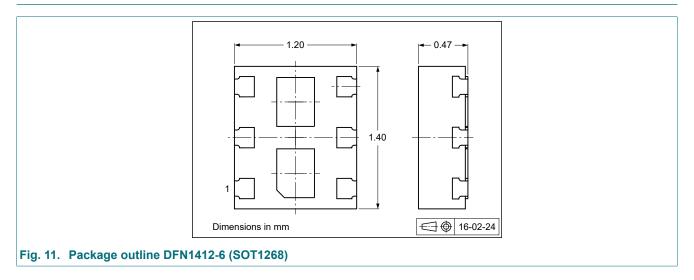
Resistor test conditions

Table 8. Resistor test conditions

Product	R1 (kΩ)	R2 (kΩ)	Test conditions				
			I ₁	l ₂	l ₃	14	
PRMH11-Q	10	10	350 µA	450 µA	-350 μA	-450 µA	

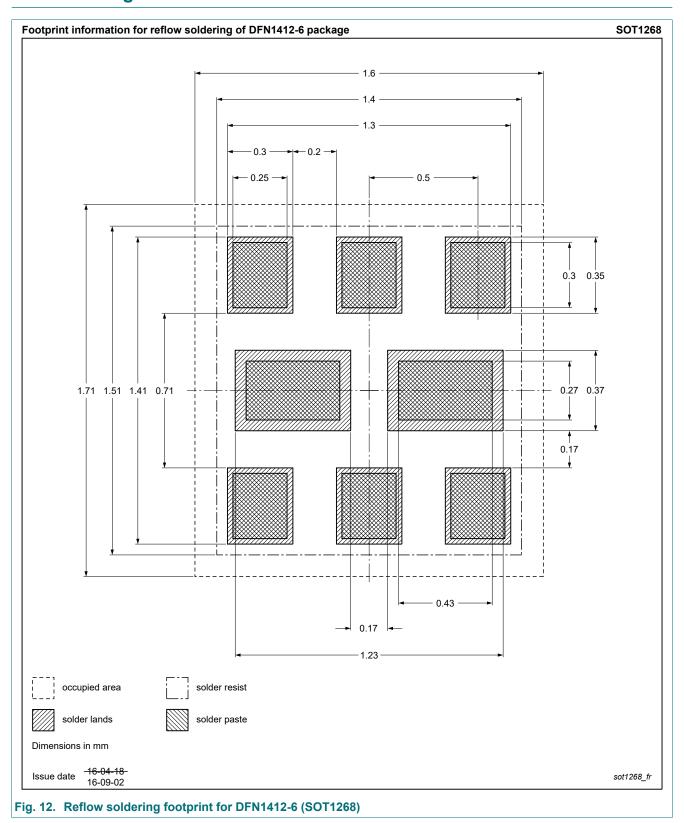
50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

12. Package outline



50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

13. Soldering



50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PRMH11-Q v.1	20250804	Product data sheet	-	-

50 V, 100 mA NPN/NPN resistor-equipped double transistor; R1 = 10 k Ω , R2 = 10 k Ω

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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